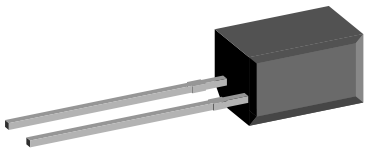
Silicon PIN Photodiode, RoHS Compliant



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FEATURES

- Package type: leaded
- Package form: side view
- Dimensions (in mm): 5 x 4 x 6.8
- Radiant sensitive area (in mm^2): 7.5
- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 65°$
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

Pb-free

e4

RoHS COMPLIANT

DESCRIPTION

BPW41N is a PIN photodiode with high speed and high radiant sensitivity in a black, side view plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

APPLICATIONS

- High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSALxxxx series IR emitters

PRODUCT SUMMARY

COMPONENT	I_{ra} (µA)	φ (deg)	$\lambda_{0.5}$ (nm)
BPW41N	45	± 65	870 to 1050

Note

Test condition see table “Basic Characteristics”

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPW41N	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	$T_{amb} \leq 25$ °C	P_V	215	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	$t \leq 5$ s	T_{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm^2	R_{thJA}	350	K/W

Note

T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Breakdown voltage	I_R = 100 µA, E = 0	$V_{(BR)}$	60			V
Reverse dark current	V_R = 10 V, E = 0	I_{ro}		2	30	nA
Diode capacitance	V_R= 0 V, f = 1 MHz, E = 0	C_D		70		pF
	V_R= 3 V, f = 1 MHz, E = 0	C_D		25	40	pF
Open circuit Voltage	E_e = 1 mW/cm², λ = 950 nm	V_o		350		mV
Temperature coefficient of V_o	E_e = 1 mW/cm², λ = 950 nm	TK_{Vo}		- 2.6		mV/K
Short circuit current	E_e = 1 mW/cm², λ = 950 nm	I_k		38		µA
Temperature coefficient of I_k	E_e = 1 mW/cm², λ = 950 nm	TK_{Ik}		0.1		%/K
Reverse light current	E_e = 1 mW/cm², λ = 950 nm, V_R = 5 V	I_{ra}	43	45		µA
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ_p		950		nm
Range of spectral bandwidth		$\lambda_{0.5}$		870 to 1050		nm
Noise equivalent power	V_R = 10 V, λ = 950 nm	NEP		4×10^{-14}		W/√ Hz
Rise time	V_R = 10 V, R_L = 1 kΩ, λ = 820 nm	t_r		100		ns
Fall time	V_R = 10 V, R_L = 1 kΩ, λ = 820 nm	t_f		100		ns

Note

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BASIC CHARACTERISTICS

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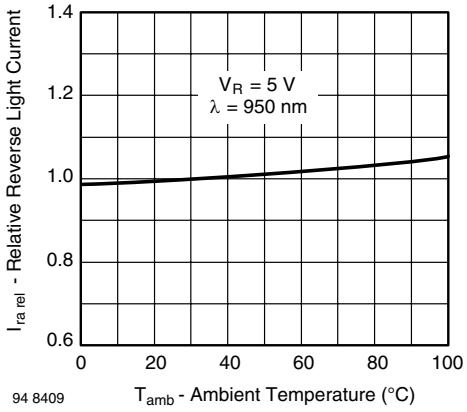


Fig. 1 - Relative Reverse Light Current vs. Ambient Temperature

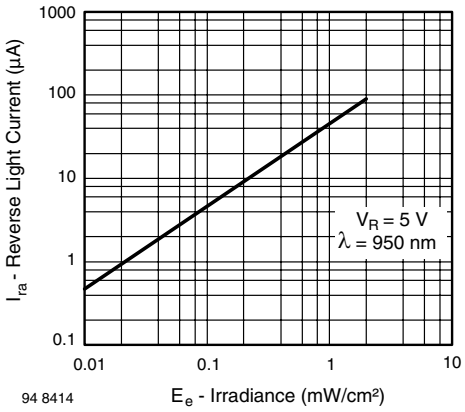


Fig. 2 - Reverse Light Current vs. Irradiance

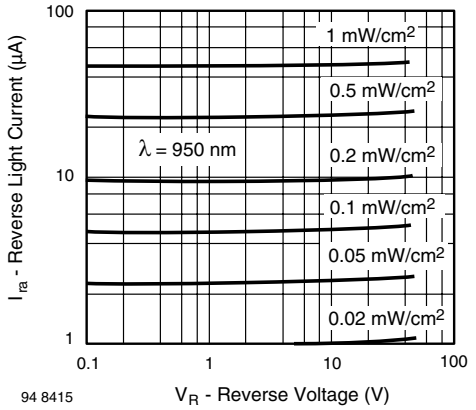


Fig. 3 - Reverse Light Current vs. Reverse Voltage

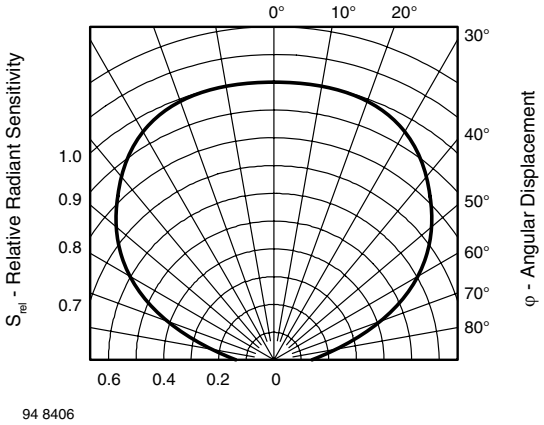


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

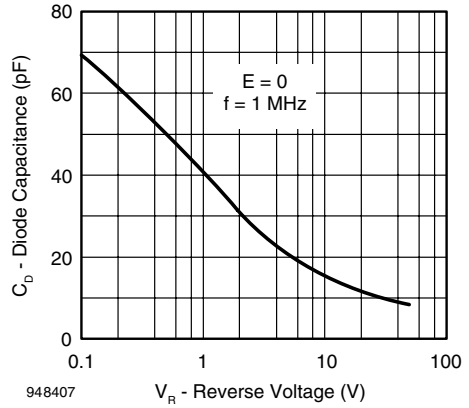


Fig. 4 - Diode Capacitance vs. Reverse Voltage

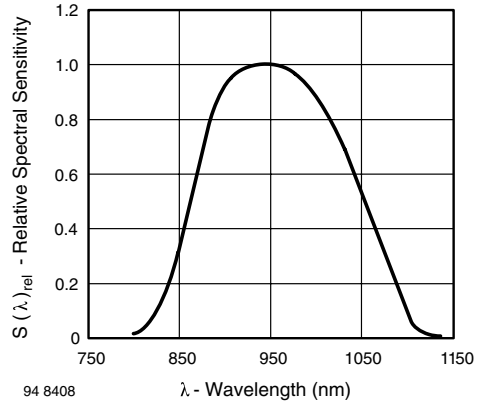
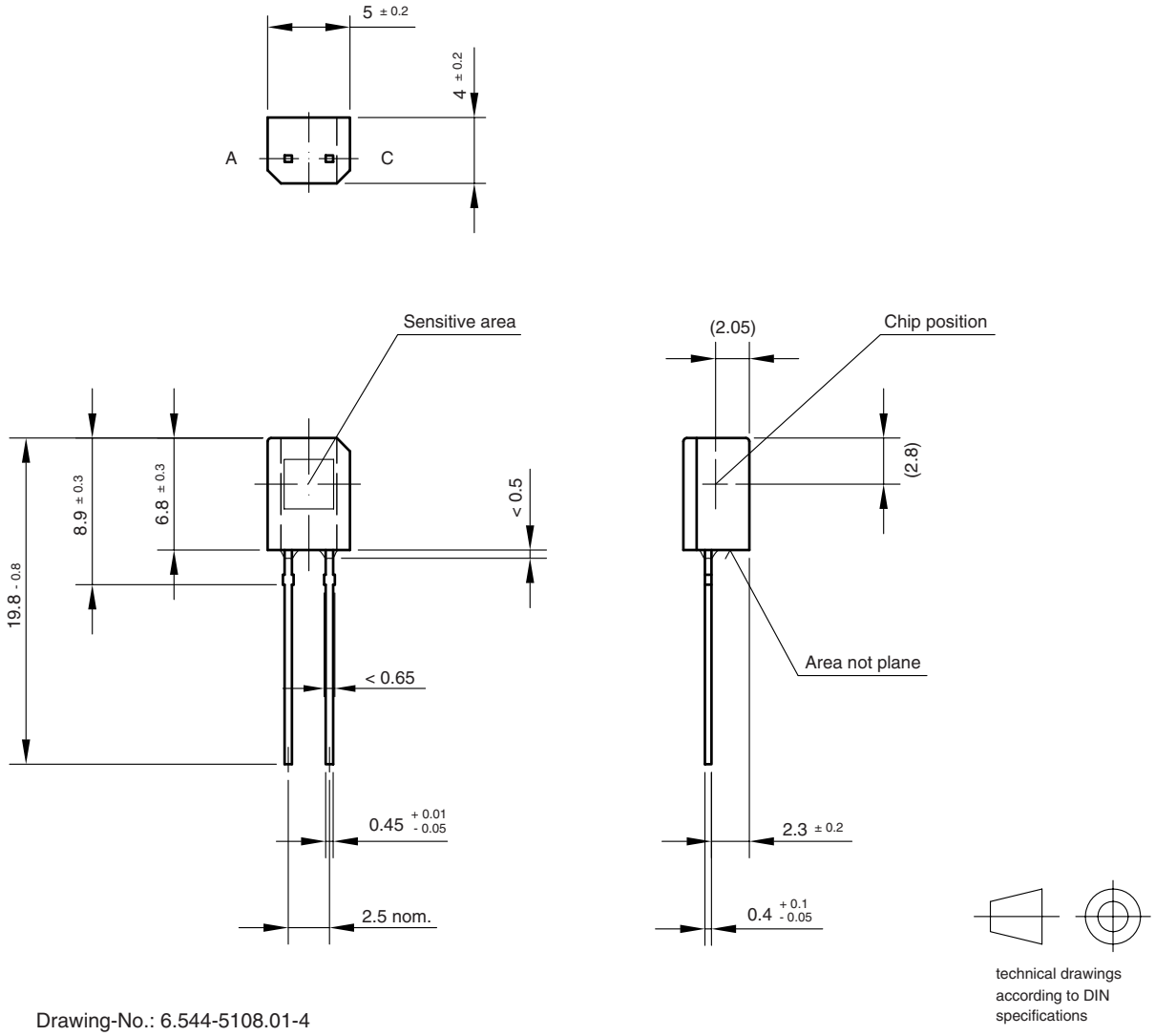


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5108.01-4
Issue:1; 01.07.96
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